μPD5759T6J

Low Noise and High Gain Amplifier IC for Impedance Converter of Microphone Data Sheet

DESCRIPTION

The μ PD5759T6J is a silicon MOS monolithic integrated circuit designed as high gain impedance converter for electret condenser microphone. This device exhibits low noise and high voltage gain characteristics. The package is a 3-pin thin-type lead-less minimold, suitable for high-density surface mounting.

FEATURES

٠	Low noise	: N _V =	-98	dBV	TYP.	$@V_{DD} =$	= 2.0 V	7, C _{in} =	= 3 pF, R _L =	= 2.2 kΩ
						-				

- : $N_V = -99 \text{ dBV TYP}$. $@V_{DD} = 2.0 \text{ V}$, $C_{in} = 5 \text{ pF}$, $R_L = 2.2 \text{ k}\Omega$ High gain
 - : $G_V = +9.0 \text{ dB TYP}$. (a) $V_{DD} = 2.0 \text{ V}$, $C_{in} = 3 \text{ pF}$, $R_L = 2.2 \text{ k}\Omega$
- : $G_V = +11.0 \text{ dB TYP}$. (a) $V_{DD} = 2.0 \text{ V}$, $C_{in} = 5 \text{ pF}$, $R_L = 2.2 \text{ k}\Omega$ • Low input capacitance : $C_{input} = 2.0 \text{ pF TYP}$. @ $V_{DD} = 2.0 \text{ V}$, $R_L = 2.2 \text{ k}\Omega$
- Low consumption current : $I_{DD} = 310 \ \mu A \ TYP.$ @V_{DD} = 2.0 V, $R_L = 2.2 \ k\Omega$
- High-density surface mounting : 3-pin thin-type lead-less minimold $(1.2 \times 1.0 \times 0.33 \text{ mm})$
- Built-in the capacitor for RF noise immunity
- High ESD voltage

APPLICATIONS

• Microphone, Sensor etc.

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μPD5759T6J-E4	μPD5759T6J-E4-A	3-pin thin-type	6Z	Embossed tape 8 mm wide
		lead-less minimold		• Pin 3 face the perforation side of the tape
		(Pb-Free)		Qty 10 kpcs/reel

Remark To order evaluation samples, please contact your nearby sales office. Part number for sample order: µPD5759T6J

CAUTION

Observe precautions when handling because these devices are sensitive to electrostatic discharge.



ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Input Voltage (IN-GND)	V _{in}	–0.5 to +0.5	V
Input Current (IN-GND)	l _{in}	0.5	mA
Output Voltage (OUT-GND)	V _{out}	0 to +5	V
Output Current (OUT-GND)	I _{out}	1	mA
Channel Temperature	T _{ch}	130	°C
Operating Ambient Temperature	T _A	-40 to +85	°C
Storage Temperature	T _{stg}	–65 to +150	°C

RECOMMENDED OPERATING RANGE (TA = +25^{\circ}C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage Note	V _{DD}	1.4	2.0	5.0	V

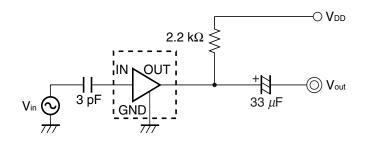
Note: $R_L = 2.2 \text{ k}\Omega$

ELECTRICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, $R_L = 2.2 \text{ k}\Omega$, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	I _{DD}	V _{DD} = 2.0 V, V _{in} = 0 V	235	310	400	μA
Input Capacitance	C _{input}	V _{DD} = 2.0 V, f = 1 MHz	-	2.0	-	pF
Voltage Gain	Gv	$\label{eq:VDD} \begin{array}{l} V_{DD} = 2.0 \text{ V}, V_{\text{in}} = 10 \text{ mVrms}, \\ C_{\text{in}} = 3 \text{ pF}, \text{f} = 1 \text{kHz}, \\ \text{see TEST CIRCUIT} \end{array}$	8.0	9.0	10.0	dB
Reduced Voltage Characteristics	⊿G _{vv}	$\label{eq:VDD} \begin{array}{l} V_{DD} = 2.0 \rightarrow 1.5 \text{ V}, \text{ V}_{in} = 10 \text{ mVrms}, \\ C_{in} = 3 \text{ pF}, \text{ f} = 1 \text{ kHz}, \\ \text{see TEST CIRCUIT} \end{array}$	_	1.0	-	dB
Frequency Characteristics	$\varDelta G_{Vf}$	$\label{eq:VDD} \begin{array}{l} V_{DD} = 2.0 \text{ V}, V_{in} = 10 \text{ mVrms}, \\ C_{in} = 3 \text{ pF}, f = 1 \text{kHz} \rightarrow 110 \text{Hz}, \\ \text{see TEST CIRCUIT} \end{array}$	_	0	-	dB
Output Noise Voltage	Nv	V_{DD} = 2.0 V, V_{in} = 0 Vrms, C_{in} = 3 pF, A-Curve, see TEST CIRCUIT	-	-98	-	dBV
Total Harmonic Distortion	THD	V_{DD} = 2.0 V, V_{out} = 50 mVrms, C_{in} = 3 pF, f = 1 kHz, see TEST CIRCUIT	_	0.3	_	%

TEST CIRCUIT

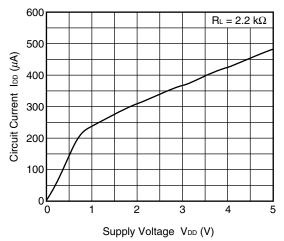
Voltage Gain, Frequency Characteristics, Output Noise Voltage, Total Harmonic Distortion



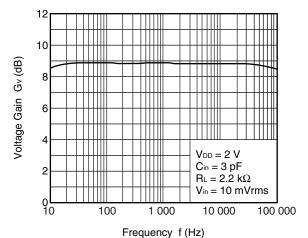


TYPICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, unless otherwise specified)

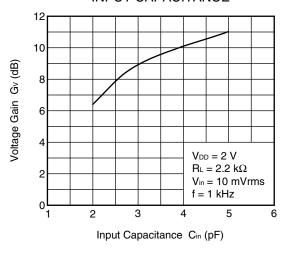
CIRCUIT CURRENT vs. SUPPLY VOLTAGE





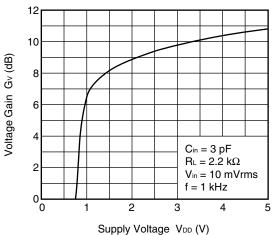




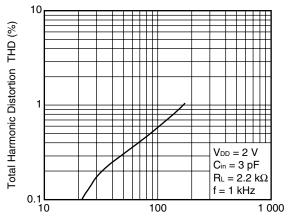




VOLTAGE GAIN vs. SUPPLY VOLTAGE

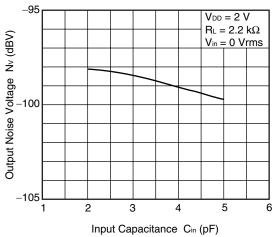


TOTAL HARMONIC DISTORTION vs. OUTPUT VOLTAGE



Output Voltage Vout (mVrms)

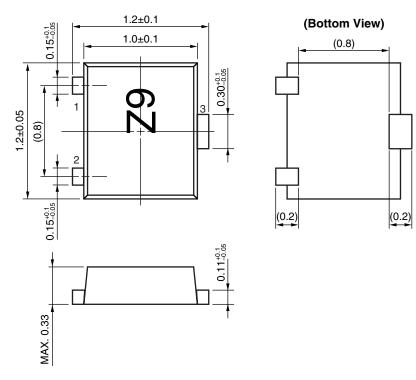
OUTPUT NOISE VOLTAGE vs. INPUT CAPACITANCE





PACKAGE DIMENSIONS

3-PIN THIN-TYPE LEAD-LESS MINIMOLD (UNIT: mm)



PIN CONNECTIONS

- 1. OUT
- 2. IN
- 3. GND





RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes		
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Wave Soldering	Peak temperature (molten solder temperature)	: 260°C or below	WS260
	Time at peak temperature	: 10 seconds or less	
	Preheating temperature (package surface temperature) : 120°C or below		
	Maximum number of flow processes	: 1 time	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Partial Heating	Peak temperature (terminal temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	

CAUTION

Do not use different soldering methods together (except for partial heating).



Revision	History
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μ PD5759T6J Data Sheet

			Description		
Rev.	Date	Page	Summary		
1.00	Apr 18, 2011	-	First edition issued		

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